STB12NM60N/-1 - STF12NM60N STP12NM60N - STW12NM60N

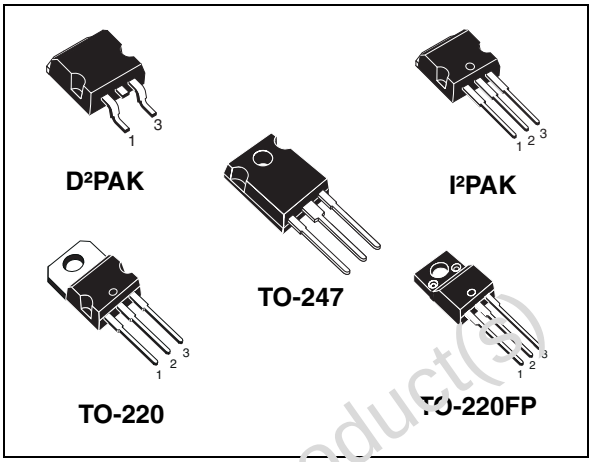
N-channel 600V - 0.35Ω - 10A - D^2/I^2PAK - TO-220/FP - TO-247
Second generation MDmesh™ Power MOSFET

Features

Type	V_{DSS} (@Tjmax)	$R_{DS(on)}$	I_D
STB12NM60N	650V	< 0.41Ω	10A
STB12NM60N-1	650V	< 0.41Ω	10A
STF12NM60N	650V	< 0.41Ω	10A(1)
STP12NM60N	650V	< 0.41Ω	10A
STW12NM60N	650V	< 0.41Ω	10A

1. Limited only by maximum temperature allowed

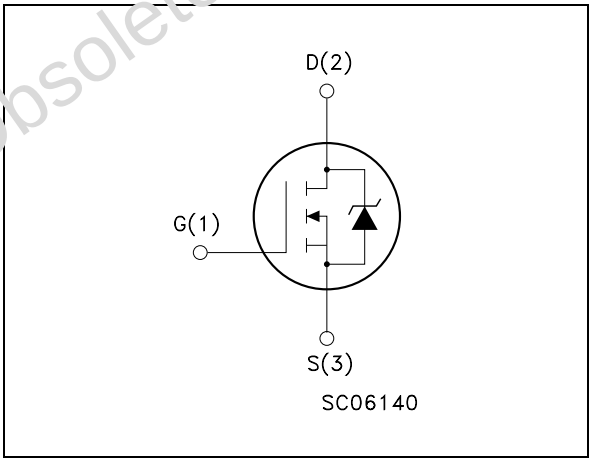
- 100% avalanche tested
- Low input capacitance and gate charge
- Low gate input resistance



Description

This series of devices implements second generation MDmesh™ technology. This revolutionary Power MOSFET associates a new vertical structure to the Company's strip layout to yield one of the world's lowest on-resistance and gate charge. It is therefore suitable for the most demanding high efficiency converters.

Internal schematic diagram



Application

- Switching application

Order codes

Part number	Marking	Package	Packaging
STB12NM60N	B12NM60N	D²PAK	Tape & reel
STB12NM60N-1	B12NM60N	I²PAK	Tube
STF12NM60N	F12NM60N	TO-220FP	Tube
STP12NM60N	P12NM60N	TO-220	Tube
STW12NM60N	W12NM60N	TO-247	Tube

Obsolete Product(s) - Obsolete Product(s)

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2 Electrical characteristics 4

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6 Revision history 17

Obsolete Product(s) - Obsolete Product(s)

1 Electrical ratings

Table 1. Absolute maximum ratings

Symbol	Parameter	Value		Unit
		D²PAK/I²PAK TO-220/TO-247	TO-220FP	
V_{DS}	Drain-source voltage (V_{GS}=0)	600		V
V_{GS}	Gate-source voltage	± 25		V
I_D	Drain current (continuous) at T_C = 25°C	10	10 (1)	A
I_D	Drain current (continuous) at T_C = 100°C	6.3	6.3 (1)	A
I_{DM} (2)	Drain current (pulsed)	40	40 (1)	A
P_{TOT}	Total dissipation at T_C = 25°C	90	25	W
dv/dt (3)	Peak diode recovery voltage slope	15		V/ns
V_{ISO}	Insulation withstand voltage (RMS) from all three leads to external heat sink (t=1s;T_C=25°C)	--	2500	V
T_j T_{stg}	Operating junction temperature Storage temperature	-55 to 150		°C

1. Limited only by maximum temperature allowed
2. Pulse width limited by safe operating area
3. I_{SD} ≤10A, di/dt ≤400A/µs, V_{DD} =80% $V_{(BR)DSS}$

Table 2. Thermal data

Symbol	Parameter	D²PAK/I²PAK TO-220/TO-247	TO-220FP	Unit
Rthj-case	Thermal resistance junction-case max	1.38	5	°C/W
Rthj-amb	Thermal resistance junction-amb max	62.5		°C/W
T_l	Maximum lead temperature for soldering purpose	300		°C

Table 3. Avalanche characteristics

Symbol	Parameter	Max value	Unit
I_{AS}	Avalanche current, repetitive or not-repetitive (pulse width limited by Tj max)	3.5	A
E_{AS}	Single pulse avalanche energy (starting Tj=25°C, I_D=I_{AS}, V_{DD}= 50V)	200	mJ

Obsolete Product(s) - Obsolete Product(s)

2 Electrical characteristics

(T_{CASE}=25°C unless otherwise specified)

Table 4. On/off states

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{(BR)DSS}$	Drain-source breakdown voltage	I_D = 1mA, V_{GS}= 0	600			V
dv/dt(1)	Drain-source voltage slope	V_{DD} = 400V,I_D = 10A, V_{GS} = 10V	41			V/ns
I_{DSS}	Zero gate voltage drain current (V_{GS} = 0)	V_{DS} = Max rating, V_{DS} = Max rating,@125°C			1 10	µA µA
I_{GSS}	Gate body leakage current (V_{DS} = 0)	V_{GS} = ±20V			100	nA
$V_{GS(th)}$	Gate threshold voltage	V_{DS}= V_{GS}, I_D = 250µA	2	3	4	V
$R_{DS(on)}$	Static drain-source on resistance	V_{GS}= 10V, I_D= 5A		0.35	0.41	Ω

1. Characteristics value at turn off on inductive load

Table 5. Dynamic

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
g_{fs}(1)	Forward transconductance	V_{DS} =15V, I_D= 5A		8		S
C_{iss} C_{oss} C_{rss}	Input capacitance Output capacitance Reverse transfer capacitance	V_{DS} = 50V, f =1MHz, V_{GS} = 0		960 65 7		pF pF pF
$C_{oss\ eq.}$(2)	Equivalent output capacitance	V_{GS} = 0, V_{DS} = 0V to 480V		180		pF
Rg	Gate input resistance	f=1MHz Gate DC Bias=0 Test signal level=20mV open drain		5		Ω
Q_g Q_{gs} Q_{gd}	Total gate charge Gate-source charge Gate-drain charge	V_{DD} = 480V, I_D = 10A V_{GS} = 10V *(see Figure 18)*		30.5 5 16		nC nC nC

1. Pulsed: pulse duration = 300µs, duty cycle 1.5%
2. $C_{oss\ eq.}$ is defined as a constant equivalent capacitance giving the same charging time as C_{oss} when V_{DS} increases from 0 to 80% V_{DSS}

Obsolete Product(s) - Obsolete Product(s)

Table 6. Switching times

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
$t_{d(on)}$ t_r $t_{d(off)}$ t_f	Turn-on delay time Rise time Turn-off delay time Fall time	V_{DD} = 300V, I_D = 5A, R_G = 4.7Ω, V_{GS} = 10V *(see Figure 17)*		15 9 60 10		ns ns ns ns

Table 7. Source drain diode

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
I_{SD} I_{SDM} (1)	Source-drain current Source-drain current (pulsed)				10 40	A A
V_{SD} (2)	Forward on voltage	I_{SD} = 10A, V_{GS}=0			1.3	V
t_{rr} Q_{rr} I_{RRM}	Reverse recovery time Reverse recovery charge Reverse recovery current	I_{SD} =10A, di/dt =100A/µs, V_{DD} = 100V, Tj = 25°C *(see Figure 19)*		360 3.5 20		ns µC A
t_{rr} Q_{rr} I_{RRM}	Reverse recovery time Reverse recovery charge Reverse recovery current	V_{DD} = 100V di/dt =100A/µs, I_{SD} = 10A Tj = 150°C *(see Figure 19)*		530 5.20 20		ns µC A

1. Pulse width limited by safe operating area
2. Pulsed: pulse duration = 300µs, duty cycle 1.5%

Obsolete Product(s) - Obsolete Product(s)

2.1 Electrical characteristics (curves)

Figure 1. Safe operating area for TO-220 / D²PAK / I²PAK

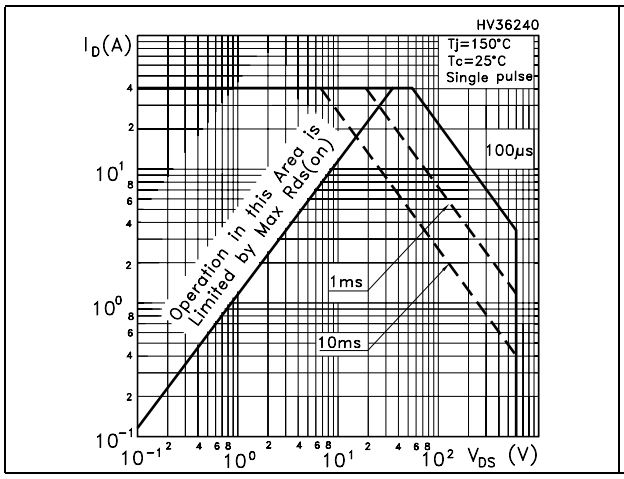


Figure 2. Thermal impedance for TO-220 / D²PAK / I²PAK

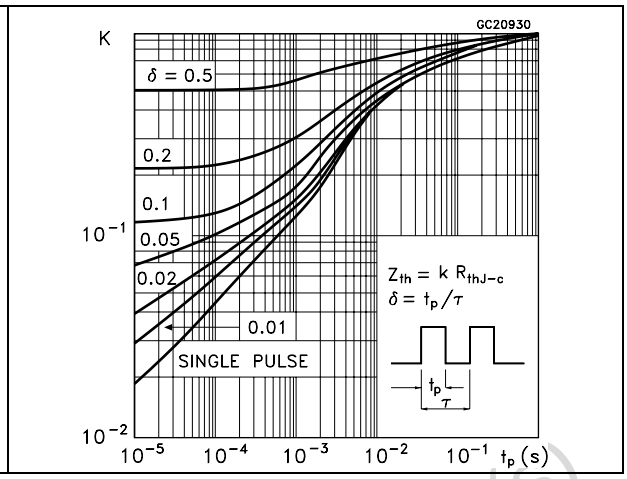


Figure 3. Safe operating area for TO-220FP

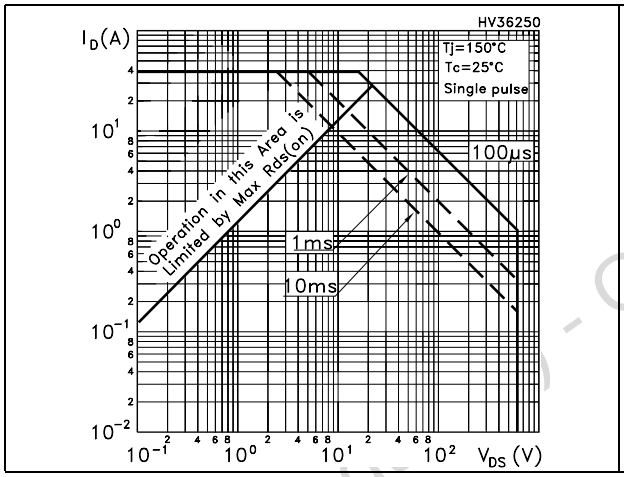


Figure 4. Thermal impedance for TO-220FP

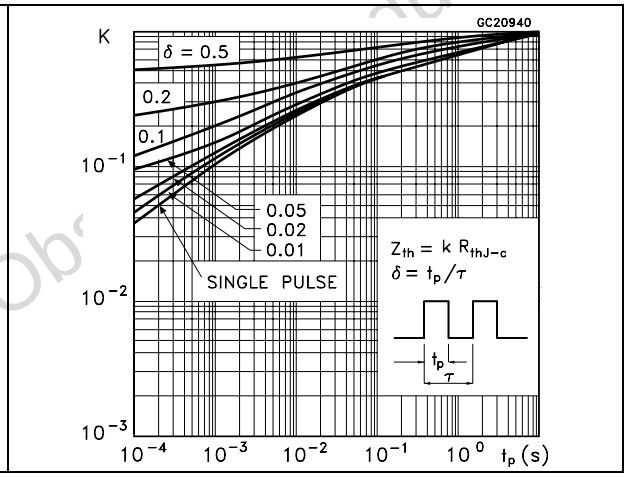


Figure 5. Safe operating area for TO-247

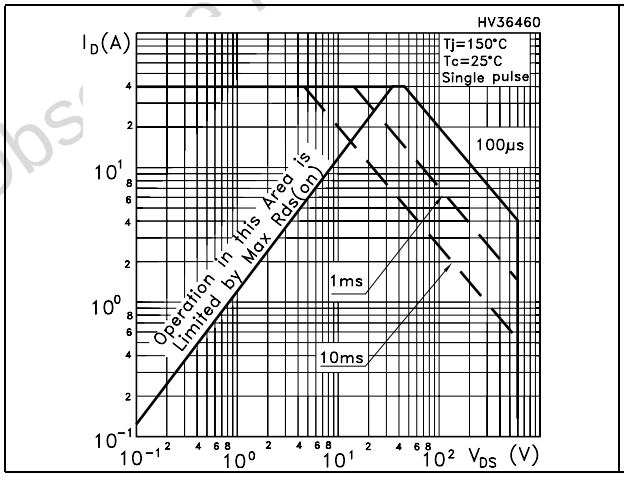
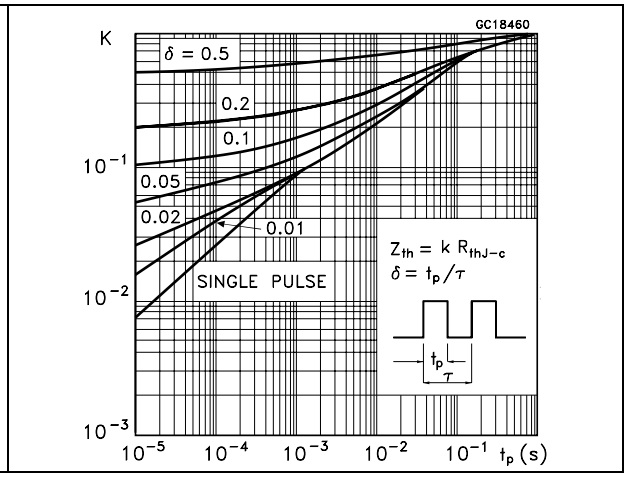


Figure 6. Thermal impedance for TO-247



Obsolete Product(s) - Obsolete Product(s)

Figure 7. Output characteristics

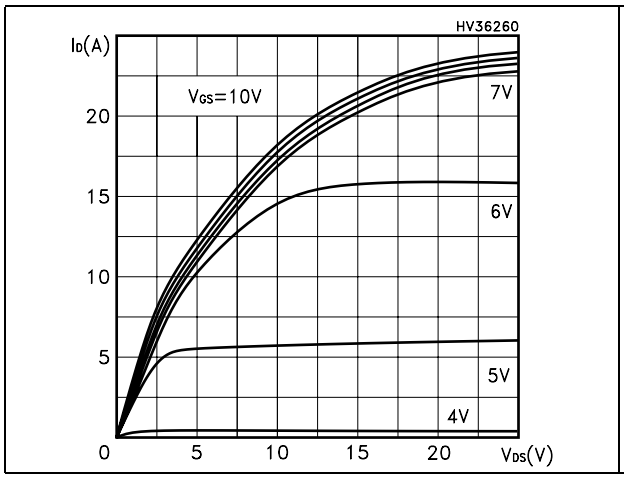


Figure 8. Transfer characteristics

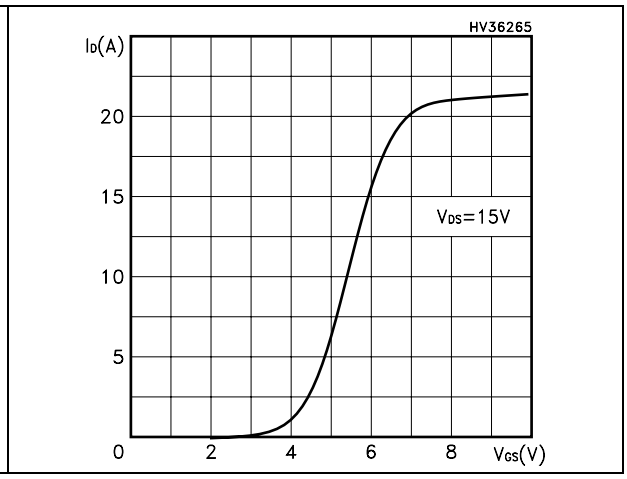


Figure 9. Transconductance

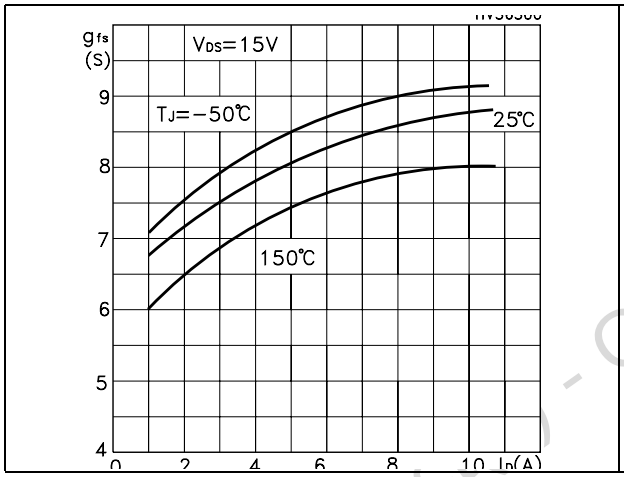


Figure 10. Static drain-source on resistance

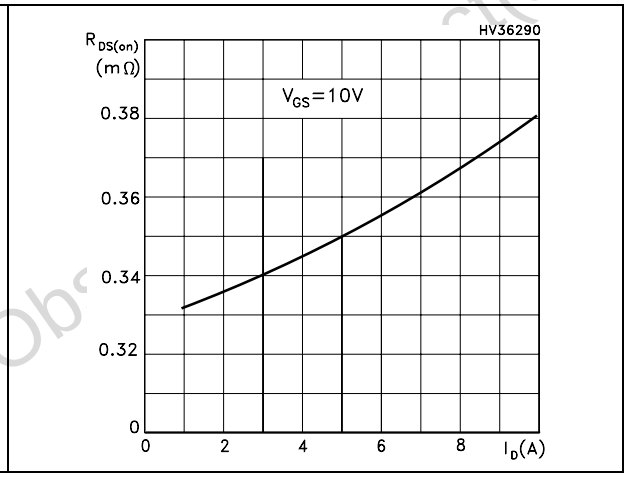


Figure 11. Gate charge vs. gate-source voltage

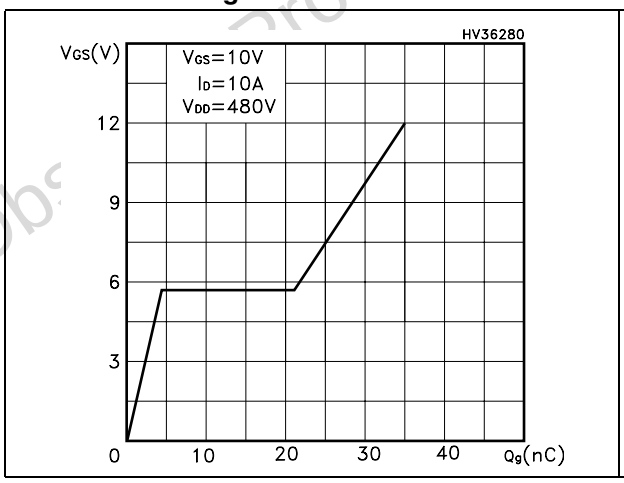
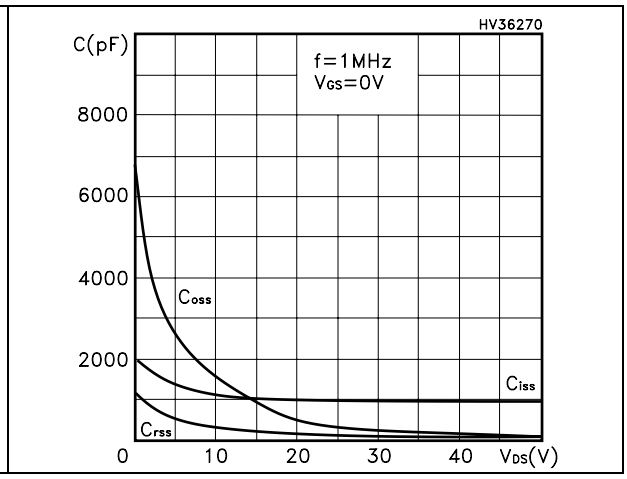


Figure 12. Capacitance variations



Obsolete Product(s) - Obs

Figure 13. Normalized gate threshold voltage vs. temperature

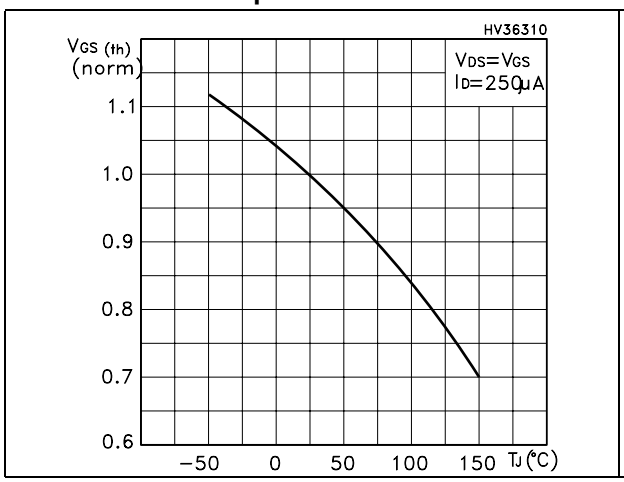


Figure 14. Normalized on resistance vs. temperature

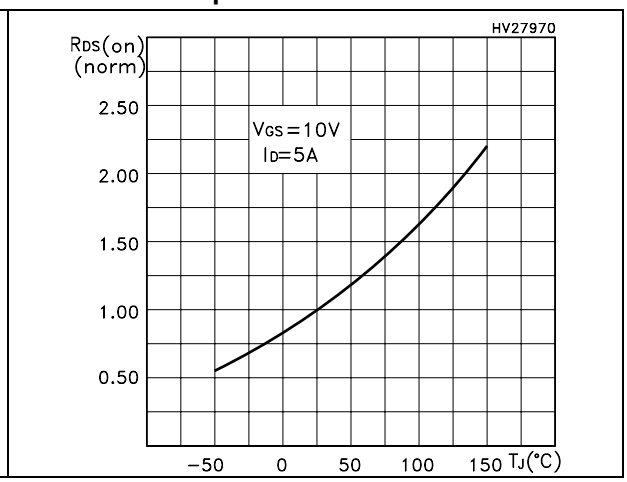


Figure 15. Source-drain diode forward characteristics

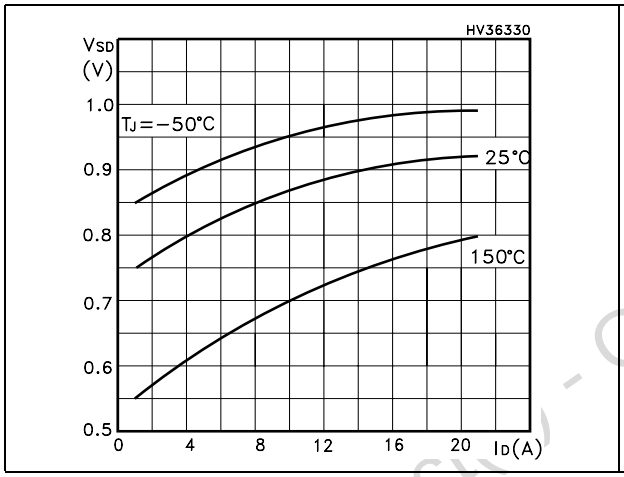
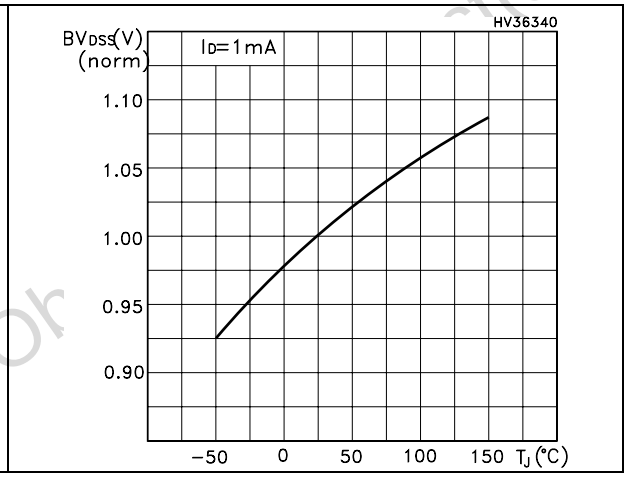


Figure 16. Normalized BV_{DSS} vs. temperature



Obsolete Product(s) - Or

3 Test circuit

Figure 17. Switching times test circuit for resistive load

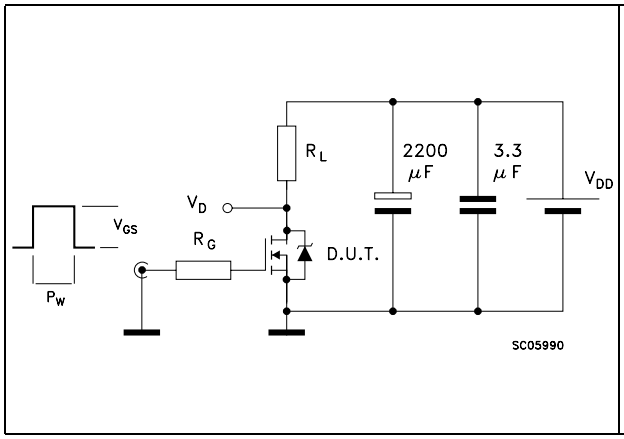


Figure 18. Gate charge test circuit

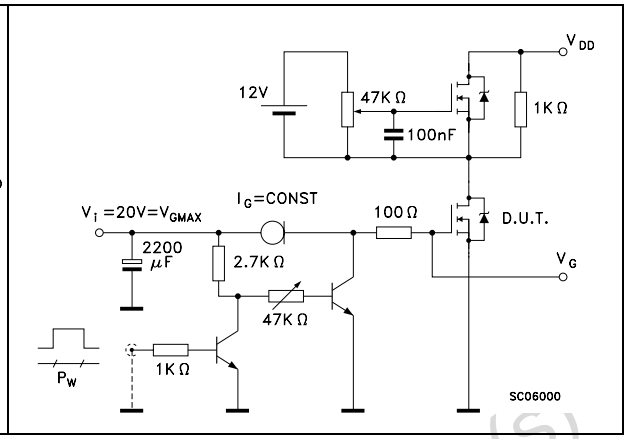


Figure 19. Test circuit for inductive load switching and diode recovery times

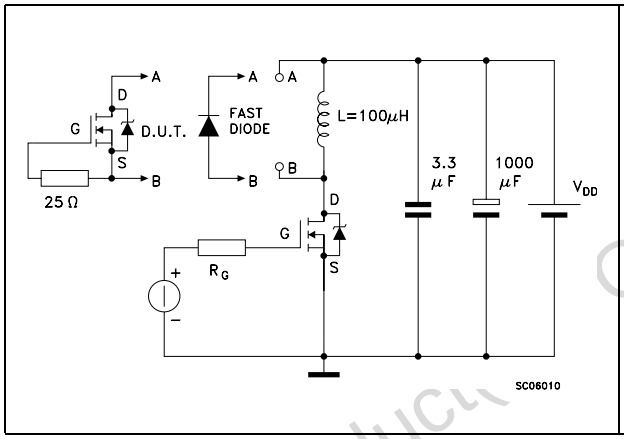


Figure 20. Unclamped Inductive load test circuit

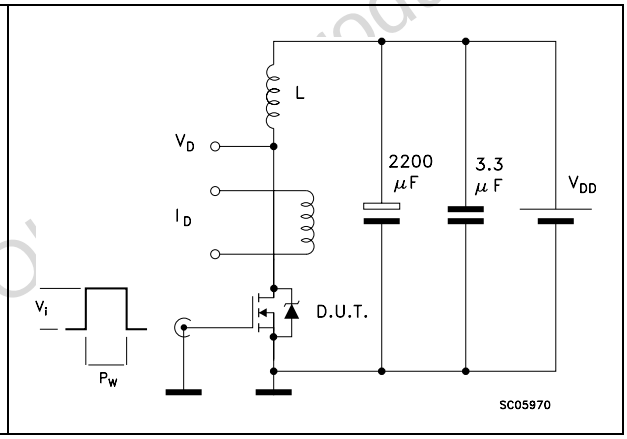


Figure 21. Unclamped inductive waveform

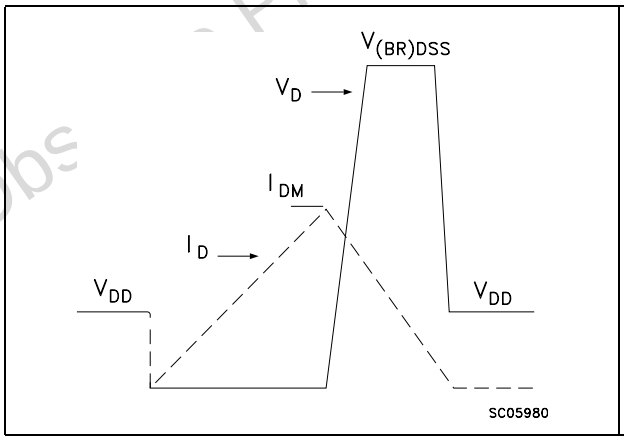
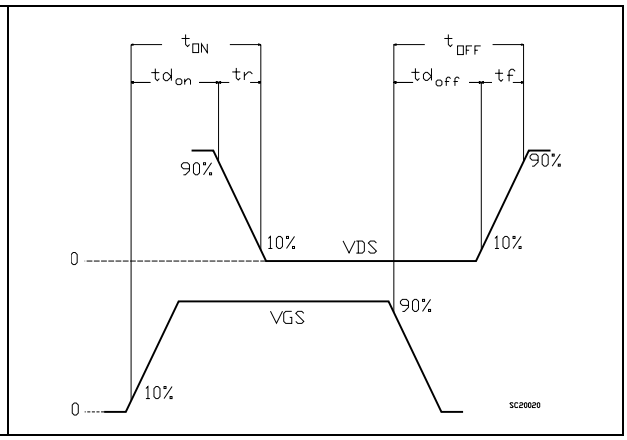


Figure 22. Switching time waveform



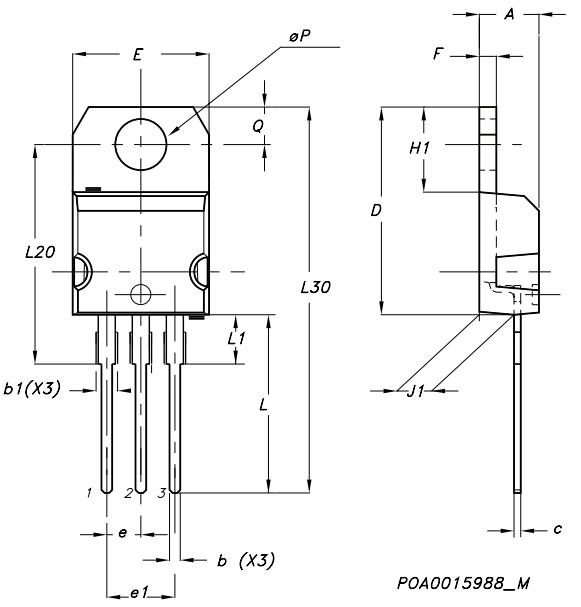
4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: *www.st.com*

Obsolete Product(s) - Obsolete Product(s)

TO-220 MECHANICAL DATA

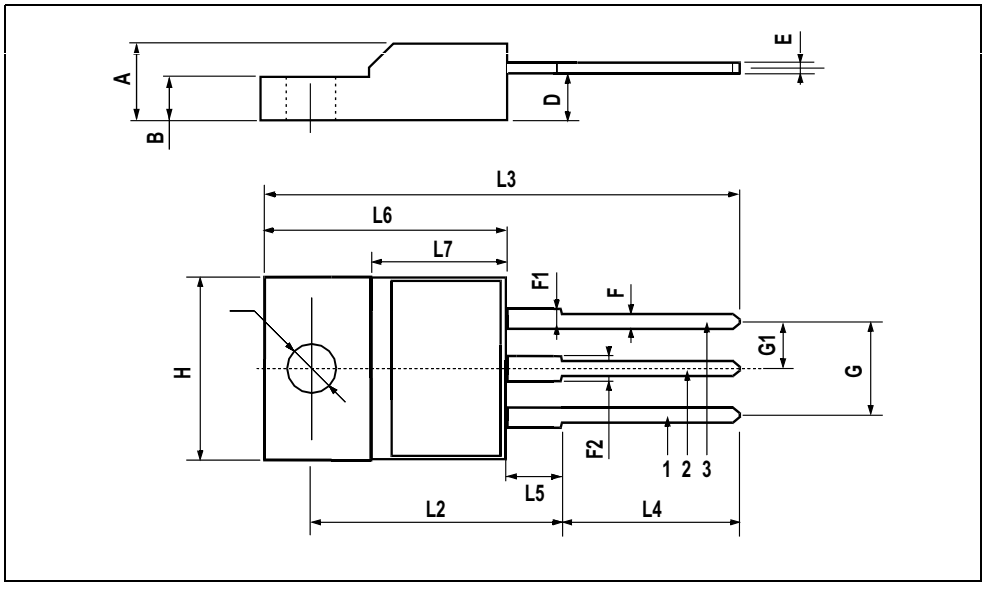
DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A	4.40		4.60	0.173		0.181
b	0.61		0.88	0.024		0.034
b1	1.15		1.70	0.045		0.066
c	0.49		0.70	0.019		0.027
D	15.25		15.75	0.60		0.620
E	10		10.40	0.393		0.409
e	2.40		2.70	0.094		0.106
e1	4.95		5.15	0.194		0.202
F	1.23		1.32	0.048		0.052
H1	6.20		6.60	0.244		0.256
J1	2.40		2.72	0.094		0.107
L	13		14	0.511		0.551
L1	3.50		3.93	0.137		0.154
L20		16.40			0.645	
L30		28.90			1.137	
øP	3.75		3.85	0.147		0.151
Q	2.65		2.95	0.104		0.116



Obsole

TO-220FP MECHANICAL DATA

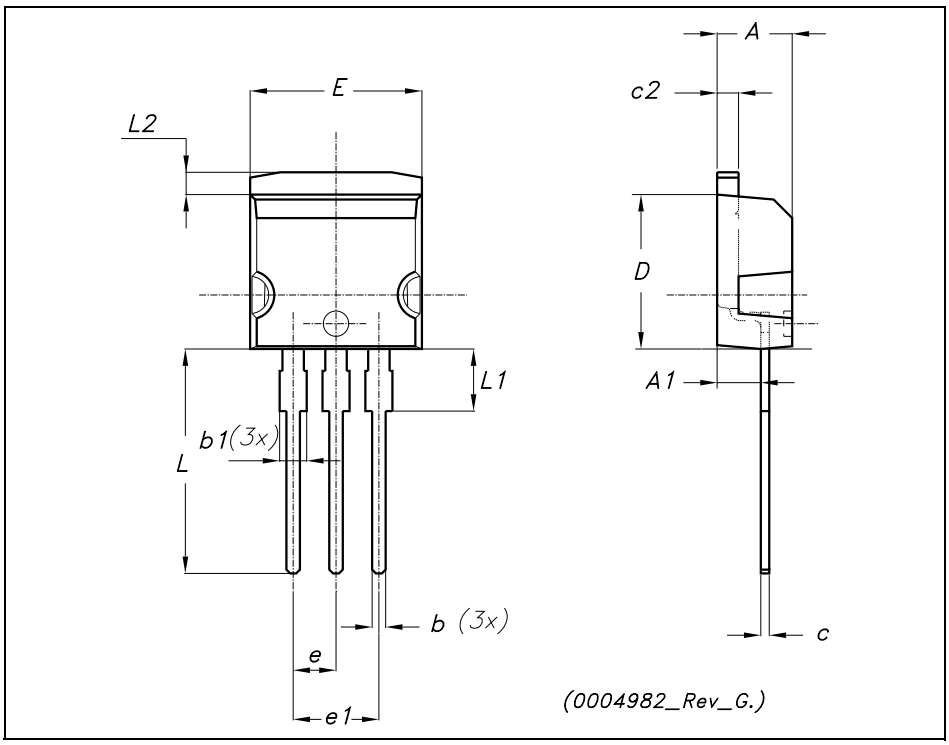
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D	2.5		2.75	0.098		0.108
E	0.45		0.7	0.017		0.027
F	0.75		1	0.030		0.039
F1	1.15		1.7	0.045		0.067
F2	1.15		1.7	0.045		0.067
G	4.95		5.2	0.195		0.204
G1	2.4		2.7	0.094		0.106
H	10		10.4	0.393		0.409
L2		16			0.630	
L3	28.6		30.6	1.126		1.204
L4	9.8		10.6	.0385		0.417
L5	2.9		3.6	0.114		0.141
L6	15.9		16.4	0.626		0.645
L7	9		9.3	0.354		0.366
Ø	3		3.2	0.118		0.126



Obsole

TO-262 (I^2PAK) MECHANICAL DATA

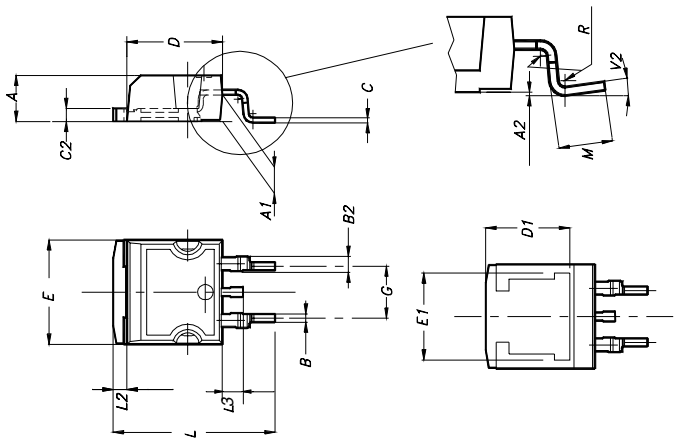
DIM.	mm.			inch		
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A	4.40		4.60	0.173		0.181
A1	2.40		2.72	0.094		0.107
b	0.61		0.88	0.024		0.034
b1	1.14		1.70	0.044		0.066
c	0.49		0.70	0.019		0.027
c2	1.23		1.32	0.048		0.052
D	8.95		9.35	0.352		0.368
e	2.40		2.70	0.094		0.106
e1	4.95		5.15	0.194		0.202
E	10		10.40	0.393		0.410
L	13		14	0.511		0.551
L1	3.50		3.93	0.137		0.154
L2	1.27		1.40	0.050		0.055



Obsole

D^2PAK MECHANICAL DATA

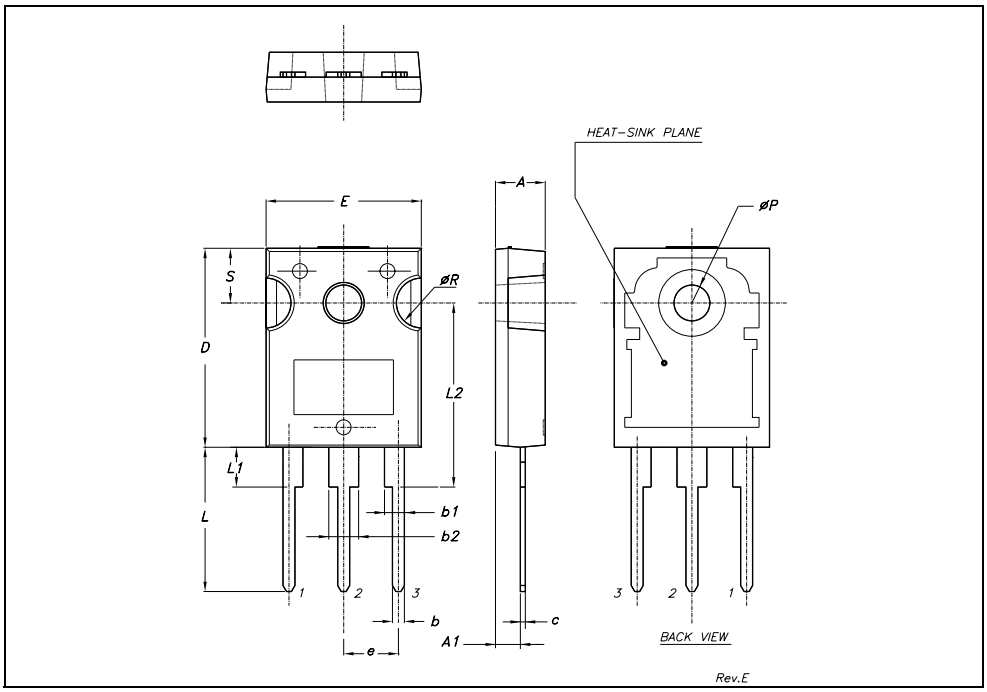
DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A	4.4		4.6	0.173		0.181
A1	2.49		2.69	0.098		0.106
A2	0.03		0.23	0.001		0.009
B	0.7		0.93	0.027		0.036
B2	1.14		1.7	0.044		0.067
C	0.45		0.6	0.017		0.023
C2	1.23		1.36	0.048		0.053
D	8.95		9.35	0.352		0.368
D1		8			0.315	
E	10		10.4	0.393		
E1		8.5			0.334	
G	4.88		5.28	0.192		0.208
L	15		15.85	0.590		0.625
L2	1.27		1.4	0.050		0.055
L3	1.4		1.75	0.055		0.068
M	2.4		3.2	0.094		0.126
R		0.4			0.015	
V2	0º		4º			



Obsole

TO-247 MECHANICAL DATA

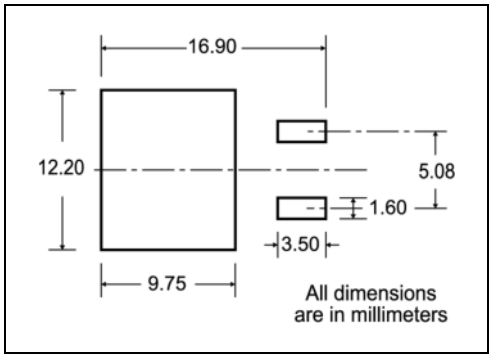
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A1	2.20		2.60	0.086		0.102
b	1.0		1.40	0.039		0.055
b1	2.0		2.40	0.079		0.094
b2	3.0		3.40	0.118		0.134
c	0.40		0.80	0.015		0.03
D	19.85		20.15	0.781		0.793
E	15.45		15.75	0.608		0.620
e		5.45			0.214	
L	14.20		14.80	0.560		0.582
L1	3.70		4.30	0.14		0.17
L2		18.50			0.728	
øP	3.55		3.65	0.140		0.143
øR	4.50		5.50	0.177		0.216
S		5.50			0.216	



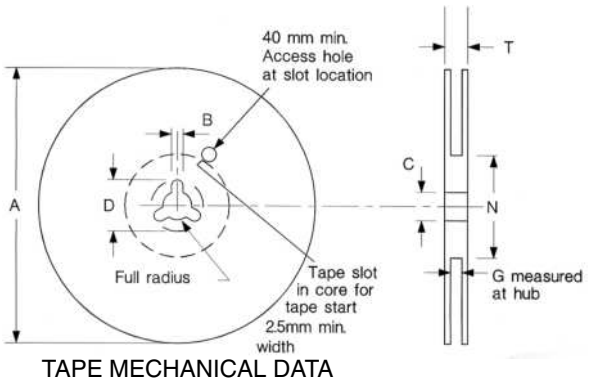
Obsole

5 Packaging mechanical data

D²PAK FOOTPRINT



TAPE AND REEL SHIPMENT



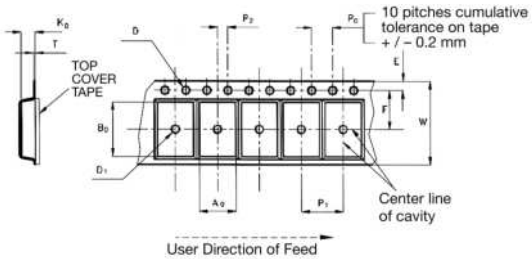
REEL MECHANICAL DATA

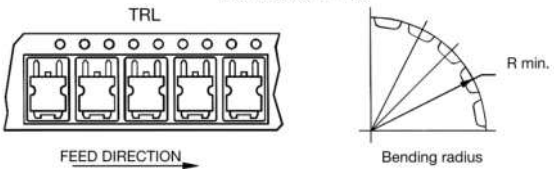
DIM.	mm		inch	
	MIN.	MAX.	MIN.	MAX.
A		330		12.992
B	1.5		0.059	
C	12.8	13.2	0.504	0.520
D	20.2		0795	
G	24.4	26.4	0.960	1.039
N	100		3.937	
T		30.4		1.197

BASE QTY	BULK QTY
1000	1000

TAPE MECHANICAL DATA

DIM.	mm		inch	
	MIN.	MAX.	MIN.	MAX.
A0	10.5	10.7	0.413	0.421
B0	15.7	15.9	0.618	0.626
D	1.5	1.6	0.059	0.063
D1	1.59	1.61	0.062	0.063
E	1.65	1.85	0.065	0.073
F	11.4	11.6	0.449	0.456
K0	4.8	5.0	0.189	0.197
P0	3.9	4.1	0.153	0.161
P1	11.9	12.1	0.468	0.476
P2	1.9	2.1	0.075	0.082
R	50		1.574	
T	0.25	0.35	0.0098	0.0137
W	23.7	24.3	0.933	0.956





* on sales type

6 Revision history

Table 8. Revision history

Date	Revision	Changes
26-Mar-2007	1	First release
23-Apr-2007	2	Complete version

Obsolete Product(s) - Obsolete Product(s)

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